

# **R6020PNJ**

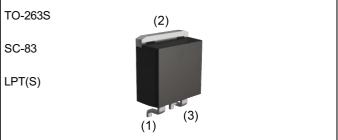
# Nch 600V 20A Power MOSFET

V <sub>DSS</sub>	600V
R <sub>DS(on)</sub> (Max.)	0.25Ω
Ι <sub>D</sub>	±20A
P <sub>D</sub>	304W

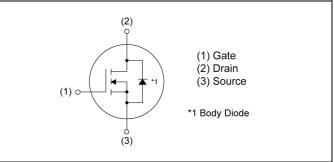
3) Gate-source voltage (V<sub>GSS</sub>) guaranteed to

5) Pb-free plating ; RoHS compliant

# ● Outline



# ●Inner circuit



# Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	24
	Quantity (pcs)	1000
	Taping code	TL
	Marking	R6020PNJ

## Application

Features

be ±30V.

1) Low on-resistance.

4) Parallel use is easy.

6) AEC-Q101 Qualified

2) Fast switching speed.

Switching Power Supply

## • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	600	V
Continuous drain current ( $T_c = 25^{\circ}C$ )	I <sub>D</sub> *1	±20	А
Pulsed drain current	I <sub>DP</sub> *2	±80	А
Gate - Source voltage	V <sub>GSS</sub>	±30	V
Avalanche current, single pulse	I <sub>AS</sub> *3	10	А
Avalanche energy, single pulse	E <sub>AS</sub> *3	26.7	mJ
Power dissipation $(T_c = 25^{\circ}C)$	P <sub>D</sub>	304	W
Junction temperature	Tj	150	°C
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C

## •Thermal resistance

Deremeter	Symbol	Values			Lincit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	$R_{thJC}^{*4}$	-	-	0.41	°C/W
Thermal resistance, junction - ambient	$R_{thJA}^{*5}$	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# •Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Sumbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		-	-	V
		V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V				
Zero gate voltage drain current	I <sub>DSS</sub>	$T_j = 25^{\circ}C$	-	-	100	μA
		T <sub>j</sub> = 125°C	-	-	-	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±30V, $V_{DS}$ = 0V	-	-	±100	nA
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	2.5	-	4.5	V
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 10A				
Static drain - source on - state resistance	R <sub>DS(on)</sub> *6	$T_j = 25^{\circ}C$	-	0.19	0.25	Ω
		T <sub>j</sub> = 125°C	-	0.37	-	
Gate resistance	R <sub>G</sub>	f = 1MHz, open drain	-	13.4	-	Ω



## • Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	C: make al	Conditions	Values			l linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Transfer Admittance	Y <sub>fs</sub>  ⁵	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10A	7	14	-	S
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	2040	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	1660	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	70	-	
Turn - on delay time	t <sub>d(on)</sub> *6	$V_{DD} \simeq 300$ V, $V_{GS}$ = 10V	-	40	-	
Rise time	t <sub>r</sub> *6	I <sub>D</sub> = 10A	-	60	-	-
Turn - off delay time	t <sub>d(off)</sub> *6	$R_L \simeq 30\Omega$	-	230	-	ns
Fall time	t <sub>f</sub> *6	R <sub>G</sub> = 10Ω	-	70	-	

# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Deremeter	Cumph of	Conditions		Values		Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{*6}$	V <sub>DD</sub> ≃ 300V	-	65	-	
Gate - Source charge	Q <sub>gs</sub> *6	I <sub>D</sub> = 20A	-	10	-	nC
Gate - Drain charge	Q <sub>gd</sub> *6	V <sub>GS</sub> = 10V	-	25	-	
Gate plateau voltage	V <sub>(plateau)</sub>	$V_{DD} \simeq 300$ V, I <sub>D</sub> = 20A	-	5.9	-	V

\*1 Limited only by maximum temperature allowed.

- \*2 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%
- \*3 L $\simeq$ 500µH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , starting T<sub>j</sub>=25°C
- \*4 T<sub>C</sub>=25°C
- \*5 Mounted on an epoxy PCB FR4 (25mm x 27mm x 0.8mm)
- \*6 Pulsed

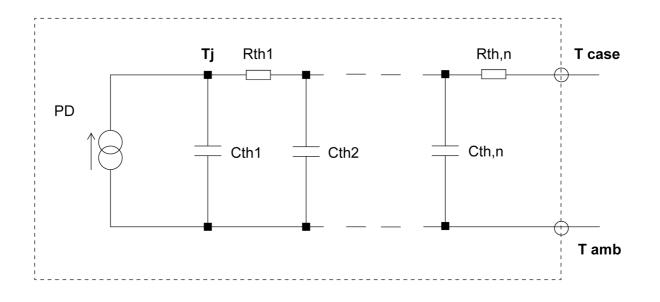


# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Sympol	Conditions		Unit			
	Symbol Conditions		Min.	Тур.	Max.	Unit	
Continuous forward current	۱ <sub>S</sub> *1	T - 25°0	-	-	20	А	
Pulse forward current	ا <sub>SP</sub> *2	T <sub>C</sub> = 25°C	-	-	80	А	
Forward voltage	V <sub>SD</sub> *4	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	-	-	1.5	V	
Reverse recovery time	t <sub>rr</sub> *4		-	493	-	ns	
Reverse recovery charge	Q <sub>rr</sub> *4	I <sub>S</sub> = 20A, V <sub>GS</sub> = di/dt = 100A/µs	-	7.43	-	μC	
Peak reverse recovery current	۲ <sub>rrm</sub> *4		-	30.2	-	А	

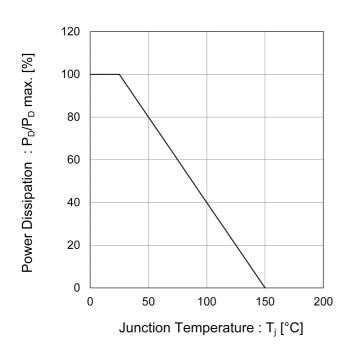
# •Typical transient thermal characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R <sub>th1</sub>	0.0462		C <sub>th1</sub>	0.00308	
R <sub>th2</sub>	0.17	K/W	C <sub>th2</sub>	0.0118	Ws/K
R <sub>th3</sub>	0.6		C <sub>th3</sub>	0.232	





## Electrical characteristic curves



## Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

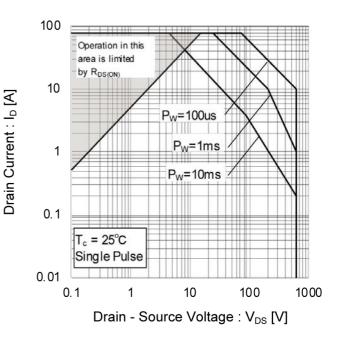
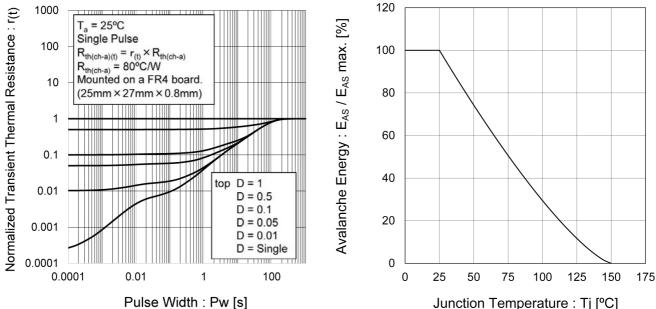


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

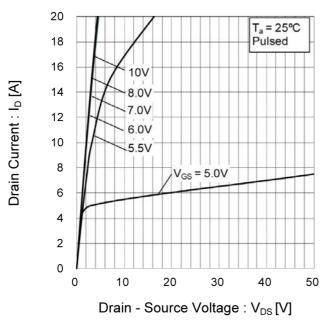
Fig.4 Avalanche Energy Derating Curve vs. Junction Temperature



Junction Temperature : Tj [°C]



## • Electrical characteristic curves



## Fig.5 Typical Output Characteristics(I)

Fig.6 Typical Output Characteristics(II)

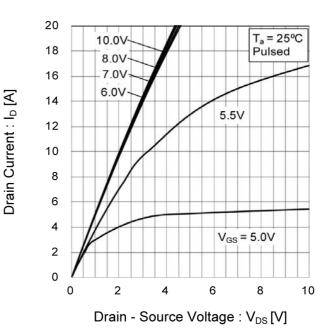


Fig.7 Tj = 150°C Typical Output Characteristics (I)



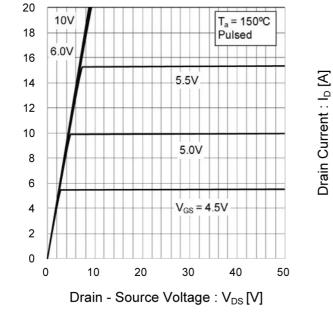
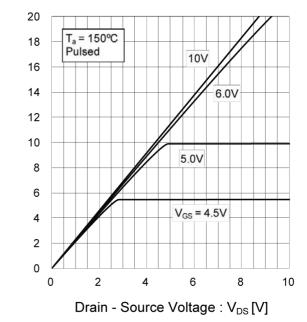
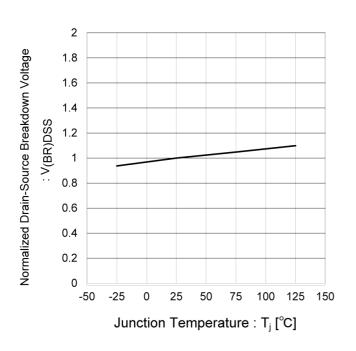


Fig.8 Tj = 150°C Typical Output Characteristics (II)

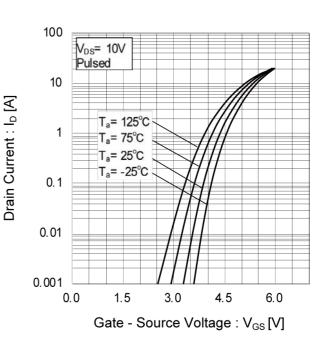




## •Electrical characteristic curves



# Fig.9 Normalized Breakdown Voltage vs. Junction Temperature



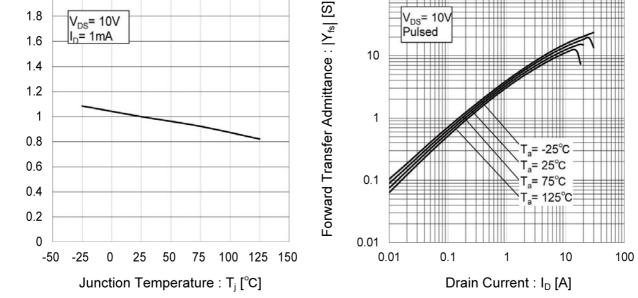
# Fig.10 Typical Transfer Characteristics

Fig.	11 Normalized Gate Threshold Voltage
VS.	Junction Temperature

Drain Current

ROHM

Fig.12 Forward Transfer Admittance vs.



2

Normalized Gate Threshold Voltage : V<sub>GS(th)</sub>



## • Electrical characteristic curves

Fig.13 Static Drain - Source On - State

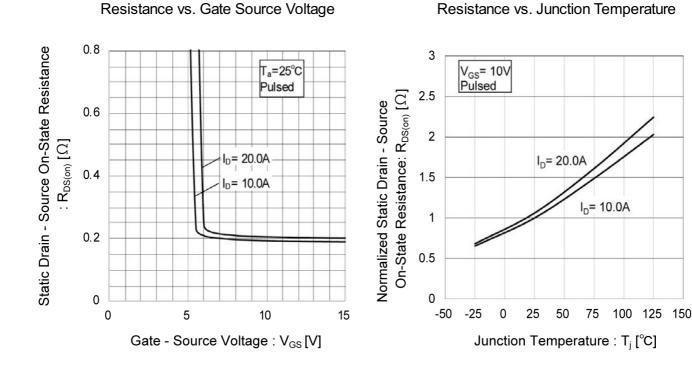


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current

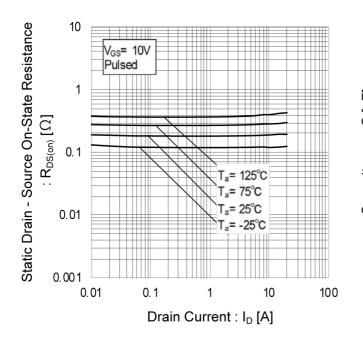
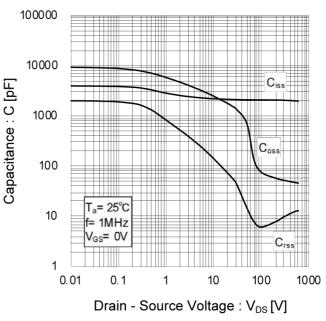
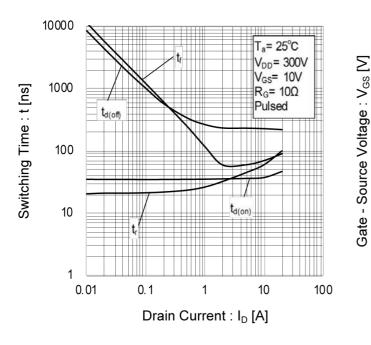


Fig.16 Typical Capacitance vs. Drain -Source Voltage

Fig.14 Static Drain - Source On - State







## Fig.17 Switching Characteristics

Fig.18 Dynamic Input Characteristics

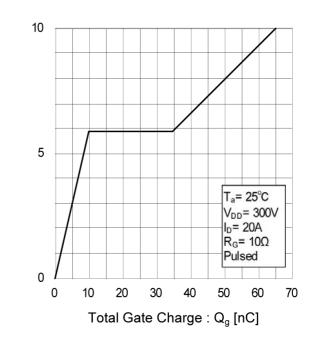
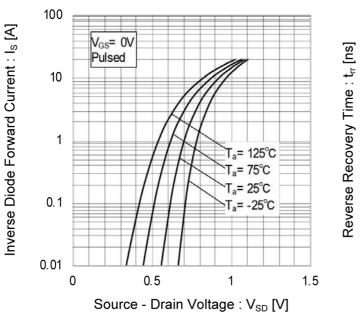
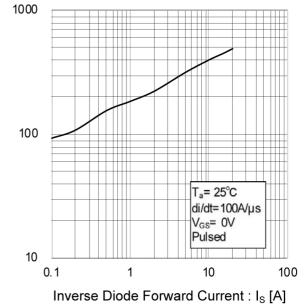


Fig.19 Inverse Diode Forward Current vs. Source - Drain Voltage

Fig.20 Reverse Recovery Time vs. Inverse Diode Forward Current







## Measurement circuits

#### Fig.1-1 Switching Time Measurement Circuit

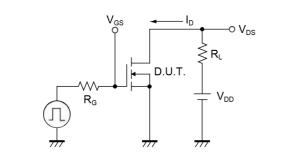


Fig.2-1 Gate Charge Measurement Circuit

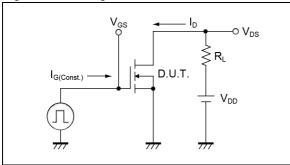


Fig.3-1 Avalanche Measurement Circuit

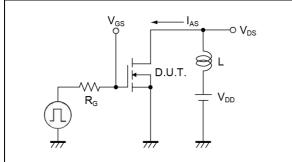


Fig.4-1 dv/dt Measurement Circuit

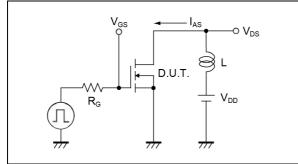
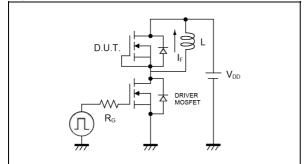
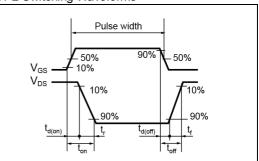


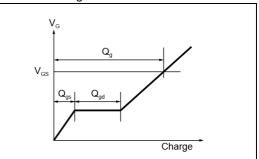
Fig.5-1 di/dt Measurement Circuit



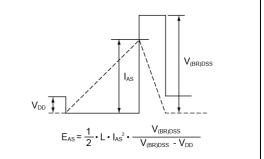
#### Fig.1-2 Switching Waveforms



#### Fig.2-2 Gate Charge Waveform



### Fig.3-2 Avalanche Waveform



### Fig.4-2 dv/dt Waveform

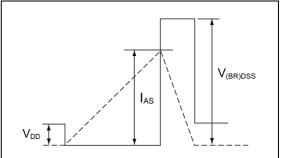
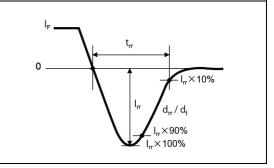
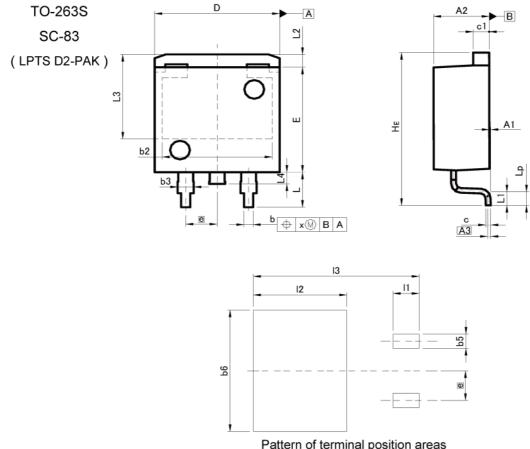


Fig.5-2 di/dt Waveform





## Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM -	MIN	MAX	MIN	MAX
A1	0.00	0.30	0.000	0.012
A2	4.30	4.70	0.169	0.185
A3	0.			010
b	0.68	0.98	0.027	0.039
b2	8.	90	0.3	350
b3	1.14	1.44	0.045	0.057
C	0.30	0.60	0.012	0.024
c1	1.10	1.50	0.043	0.059
D	9.80	10.40	0.386	0.409
E	8.80	9.20	0.346	0.362
e	2.	54	0.1	00
HE	12.80	13.40	0.504	0.528
L	2.70	3.30	0.106	0.130
L1	1.	20	0.047	
L2	1.	10	0.043	
L3	7.	7.25		285
L4	1.	00	0.0	)39
Lp	0.90	1.50	0.035	0.059
x	志)	0.25	-	0.010
	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
b5		1.23	-	0.049
b6	-	10.40		0.409
11	<u>19</u> 8	2.10	<u>, 12</u>	0.083
12		7.55	1. 1.	0.297
13	<del></del>	13.40		0.528

Dimension in mm/inches





# Notice

#### **Precaution on using ROHM Products**

 If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN	USA	EU	CHINA
CLASSII	CLASSI	CLASS II b	CLASSⅢ
CLASSⅣ		CLASSII	

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  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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